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## **Supporting Information**

## Core-shell nanostructures introduce multiple potential barriers to enhance energy filtering for the improvement of thermoelectric properties of SnTe

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## Results and Discussion:

In our work, the Lorenz number is obtained based on the two band model:

$$L_{lh} = \left(\frac{\kappa_B}{e}\right)^2 \left[ \frac{{}^2F_{-2}^1(\eta, \alpha)}{{}^0F_{-2}^1(\eta, \alpha)} - \left(\frac{{}^1F_{-2}^1(\eta, \alpha)}{{}^0F_{-2}^1(\eta, \alpha)}\right)^2 \right], \tag{1}$$

and

$$L_{hh} = \left(\frac{\kappa_B}{e}\right)^2 \left[\frac{{}^{2}F_{-2}^{1}(\eta - \Delta v, 0)}{{}^{0}F_{-2}^{1}(\eta - \Delta v, 0)} - \left(\frac{{}^{1}F_{-2}^{1}(\eta - \Delta v, 0)}{{}^{0}F_{-2}^{1}(\eta - \Delta v, 0)}\right)^2\right], \quad (2)$$

In the equations above the integral  ${}^{n}F_{l}^{m}$  is defined by

$${}^{n}F_{l}^{m} = \int_{0}^{\infty} -\frac{\partial f}{\partial \varepsilon} \varepsilon^{n} \left(\varepsilon + \alpha \varepsilon^{2}\right)^{m} \left[\left(1 + 2\alpha \varepsilon\right)^{2} + 2\right]^{\frac{l}{2}} d\varepsilon,$$

where  $L_{lh}$  is the L of light-hole band,  $L_{hh}$  is the L of heavy-hole band,  $\eta$  is the reduced chemical potential calculated by  $\eta = E_f/k_BT$ ,  $\alpha$  is the nonparabolic parameter obtained by  $\alpha = k_BT/E_g$ , and  $^nF_l^m$  is the generalized Fermi function. For the second valence band, we set  $\alpha = 0$  and replace  $\eta$  with  $\eta$ - $\Delta v$  in these equations, where  $\Delta v = \Delta E/k_BT$ ,  $\Delta E$  is the energy difference between the first and second valence band. The total L of the

system can be expressed:

$$L_{\text{total}} = (\delta_{lh} L_{lh} + \delta_{hh} L_{hh}) / (\delta_{lh} + \delta_{hh}). \tag{3}$$

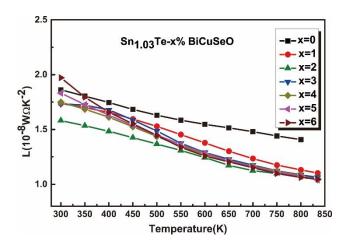


Figure S1. Lorenz numbers as a function of temperature for Sn<sub>1.03</sub>Te-x% BiCuSeO.